





# 6-Pin DIP Zero-Cross Optoisolators Triac Driver Output (400 Volts Peak)

The MOC3041, MOC3042 and MOC3043 devices consist of gallium arsenide infrared emitting diodes optically coupled to a monolithic silicon detector performing the function of a Zero Voltage Crossing bilateral triac driver.

They are designed for use with a triac in the interface of logic systems to equipment powered from 115 Vac lines, such as solid–state relays, industrial controls, motors, solenoids and consumer appliances, etc.

- Simplifies Logic Control of 115 Vac Power
- · Zero Voltage Crossing
- dv/dt of 2000 V/μs Typical, 1000 V/μs Guaranteed
- To order devices that are tested and marked per VDE 0884 requirements, the suffix "V" must be included at end of part number. VDE 0884 is a test option.

### Recommended for 115/240 Vac(rms) Applications:

Solenoid/Valve Controls

Total Power Dissipation @ TA = 25°C

Ambient Operating Temperature Range(2)

Derate above 25°C

Junction Temperature Range

Storage Temperature Range(2)

Soldering Temperature (10 s)

- Lighting Controls
- Static Power Switches
- AC Motor Drives

- Temperature Controls
- E.M. Contactors
- AC Motor Starters
- Solid State Relays

 $P_{\mathsf{D}}$ 

TJ

 $T_A$ 

Tstg

250

2.94

-40 to +100

-40 to +85

-40 to +150

260

mW

mW/°C

°C

°C

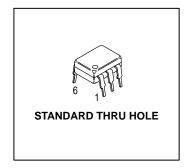
°C

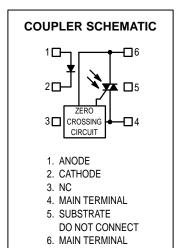
## **MAXIMUM RATINGS** (T<sub>A</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
INFRARED EMITTING DIODE	·	·	
Reverse Voltage	٧R	6	Volts
Forward Current — Continuous	ΙF	60	mA
Total Power Dissipation @ T <sub>A</sub> = 25°C Negligible Power in Output Driver	PD	120	mW
Derate above 25°C		1.41	mW/°C
OUTPUT DRIVER			
Off-State Output Terminal Voltage	V <sub>DRM</sub>	400	Volts
Peak Repetitive Surge Current (PW = 100 μs, 120 pps)	ITSM	1	A
Total Power Dissipation @ T <sub>A</sub> = 25°C	PD	150	mW
Derate above 25°C		1.76	mW/°C
TOTAL DEVICE			
Isolation Surge Voltage <sup>(1)</sup> (Peak ac Voltage, 60 Hz, 1 Second Duration)	VISO	7500	Vac(pk)

## Isolation surge voltage, V<sub>ISO</sub>, is an internal device dielectric breakdown rating. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.

# MOC3041 MOC3042 MOC3043





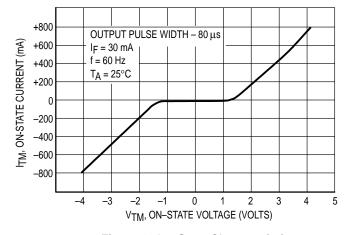
## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
INPUT LED			•		
Reverse Leakage Current (V <sub>R</sub> = 6 V)	IR	_	0.05	100	μА
Forward Voltage (I <sub>F</sub> = 30 mA)	VF	_	1.3	1.5	Volts
OUTPUT DETECTOR (I <sub>F</sub> = 0 unless otherwise noted)			•	•	•
Leakage with LED Off, Either Direction (Rated V <sub>DRM</sub> <sup>(1)</sup> )	I <sub>DRM1</sub>	_	2	100	nA
Peak On–State Voltage, Either Direction (I <sub>TM</sub> = 100 mA Peak)	VTM	_	1.8	3	Volts
Critical Rate of Rise of Off–State Voltage <sup>(3)</sup>	dv/dt	1000	2000	_	V/μs
COUPLED	•				
LED Trigger Current, Current Required to Latch Output (Main Terminal Voltage = 3 V <sup>(2)</sup> )  MOC3041  MOC3042  MOC3043	lFT	_ _ _	_ _ _	15 10 5	mA
Holding Current, Either Direction	lн	<u> </u>	250	_	μА
Isolation Voltage (f = 60 Hz, t = 1 sec)	V <sub>ISO</sub>	7500	_	_	Vac(pk)
ZERO CROSSING	•				
Inhibit Voltage (IF = Rated IFT, MT1-MT2 Voltage above which device will not trigger.)	VIH	_	5	20	Volts
Leakage in Inhibited State (IF = Rated IFT, Rated VDRM, Off State)	I <sub>DRM2</sub>		_	500	μА

- 1. Test voltage must be applied within dv/dt rating.
- 2. All devices are guaranteed to trigger at an IF value less than or equal to max IFT. Therefore, recommended operating IF lies between IFT (15 mA for MOC3041, 10 mA for MOC3042, 5 mA for MOC3043) and absolute max IF (60 mA).
- 3. This is static dv/dt. See Figure 7 for test circuit. Commutating dv/dt is a function of the load-driving thyristor(s) only.

## TYPICAL ELECTRICAL CHARACTERISTICS







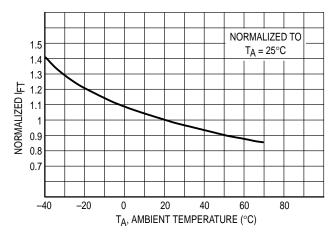


Figure 2. Trigger Current versus Temperature



## MOC3041, MOC3042, MOC3043

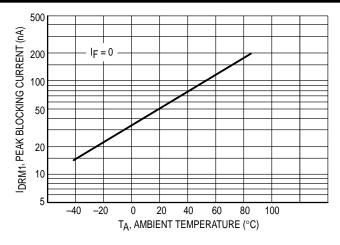


Figure 3. I<sub>DRM1</sub>, Peak Blocking Current versus Temperature

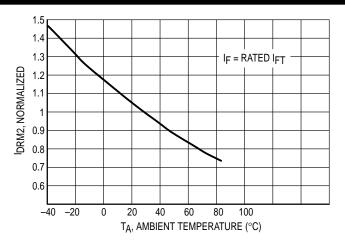


Figure 4. IDRM2, Leakage in Inhibit State versus Temperature

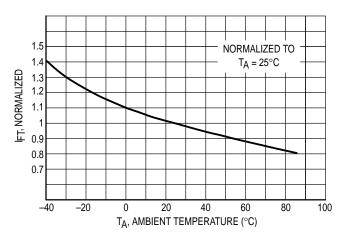


Figure 5. Trigger Current versus Temperature

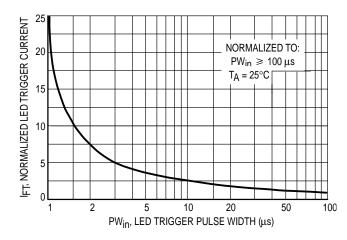
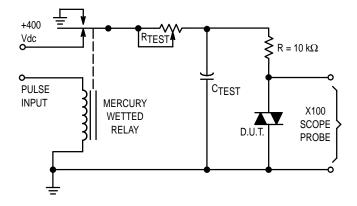


Figure 6. LED Current Required to Trigger versus LED Pulse Width



- 1. The mercury wetted relay provides a high speed repeated pulse to the D.U.T.
- 2. 100x scope probes are used, to allow high speeds and voltages.
- 3. The worst–case condition for static dv/dt is established by triggering the D.U.T. with a normal LED input current, then removing the current. The variable RTEST allows the dv/dt to be gradually increased until the D.U.T. continues to trigger in response to the applied voltage pulse, even after the LED current has been removed. The dv/dt is then decreased until the D.U.T. stops triggering. τRC is measured at this point and recorded.

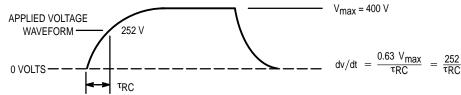
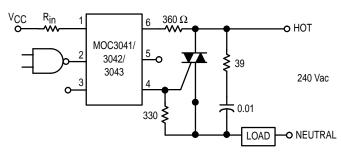


Figure 7. Static dv/dt Test Circuit



## MOC3041, MOC3042, MOC3043



\* For highly inductive loads (power factor < 0.5), change this value to 360 ohms.

Typical circuit for use when hot line switching is required. In this circuit the "hot" side of the line is switched and the load connected to the cold or neutral side. The load may be connected to either the neutral or hot line.

 $R_{\mbox{\scriptsize in}}$  is calculated so that IF is equal to the rated IFT of the part, 5 mA for the MOC3043, 10 mA for the MOC3042, or 15 mA for the MOC3041. The 39 ohm resistor and 0.01  $\mu F$  capacitor are for snubbing of the triac and may or may not be necessary depending upon the particular triac and load used.

Figure 8. Hot-Line Switching Application Circuit

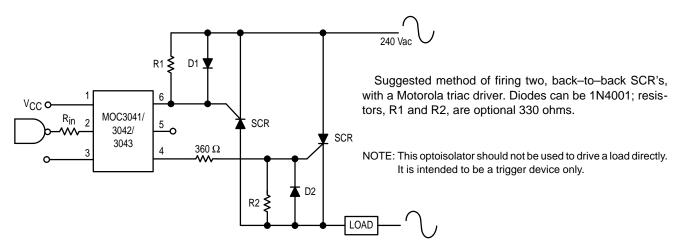
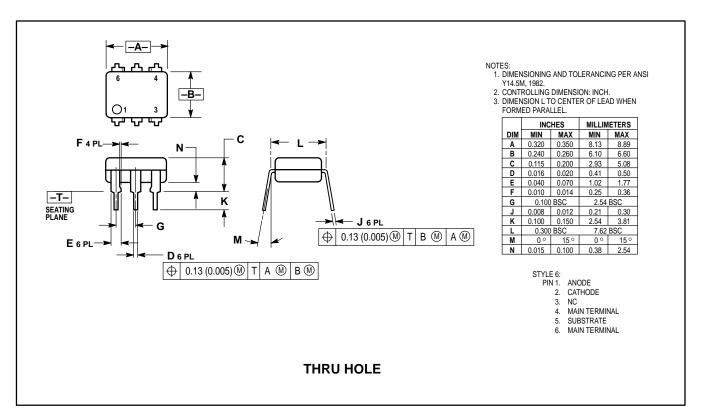
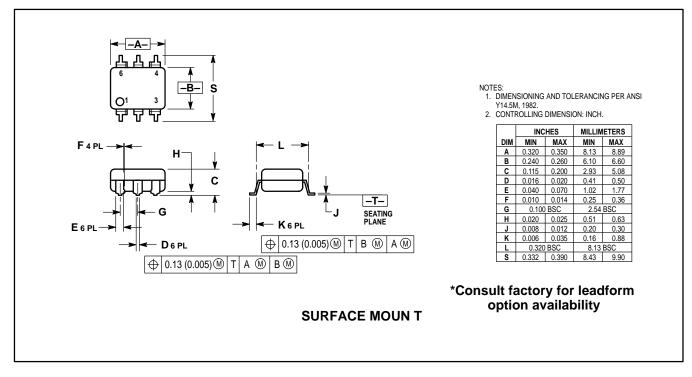


Figure 9. Inverse-Parallel SCR Driver Circuit



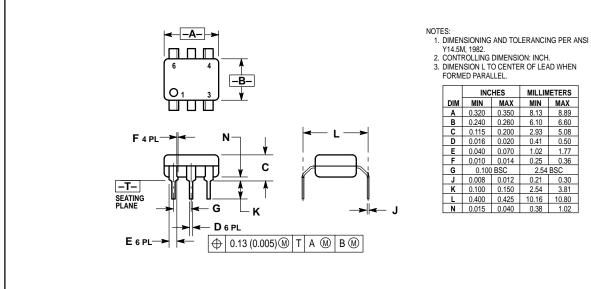
## **PACKAGE DIMENSIONS**







## MOC3041, MOC3042, MOC3043



	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.320	0.350	8.13	8.89	
В	0.240	0.260	6.10	6.60	
С	0.115	0.200	2.93	5.08	
D	0.016	0.020	0.41	0.50	
E	0.040	0.070	1.02	1.77	
F	0.010	0.014	0.25	0.36	
G	0.100	0.100 BSC		BSC	
J	0.008	0.012	0.21	0.30	
K	0.100	0.150	2.54	3.81	
L	0.400	0.425	10.16	10.80	
N	0.015	0.040	0.38	1.02	

0.4 LEAD SPACING



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